

Lonten N-channel 40V, 120A, 2.8m Ω Power MOSFET

Description	Product Summary
These N-Channel enhancement mode power field	V _{DSS} 40V
effect transistors are using split gate trench DMOS	$R_{DS(on),max}$ (V_{GS} =10V 2.8m Ω
technology. This advanced technology has been	ID 120A
especially tailored to minimize on-state resistance,	
provide superior switching performance, and with	
stand high energy pulse in the avalanche and	Pin Configuration
commutation mode. These devices are well suited	
for high efficiency fast switching applications.	
Features	All's ages
 40V,120A, R_{DS(on),max} = 2.8mΩ@V_{GS} = 10V 	
Improved dv/dt capability	TO-251 TO-252
Fast switching	9
100% EAS Guaranteed	D
Green device available	
Applications	
Motor Drives	• S
♦ UPS	
DC-DC Converter	N-Channel MOSFET

Absolute Maximum Ratings Tc = 25°C unless otherwise noted

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	40	V
Continuous drain current (T_c = 25°C) ¹⁾		120	A
Continuous drain current (T_c = 100°C)	ID	81	А
Pulsed drain current ²⁾	I _{DM}	360	А
Gate-Source voltage	V _{GSS}	±18	V
Avalanche energy ³⁾	E _{AS}	225	mJ
Power Dissipation ($T_c = 25^{\circ}C$)	P _D	57.6	W
Storage Temperature Range	T _{STG}	-55 to +150	°C
Operating Junction Temperature Range	TJ	-55 to +150	°C

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R _{eJC}	1.67	°C/W



Package Marking and Ordering Information

Device	Device Package	Marking
LSGH04R028	TO-251	LSGH04R028
LSGG04R028	TO-252	LSGG04R028

Electrical Characteristics T_J = 25°C unless otherwise noted

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Static characteristics						
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0 V, I _D =250uA	40			V
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.0		2.2	V
Drain-source leakage current	I _{DSS}	V _{DS} =40 V, V _{GS} =0V, T _J = 25°C			1	μA
Gate leakage current, Forward	I _{GSSF}	V _{GS} =20 V, V _{DS} =0 V			100	nA
Gate leakage current, Reverse	I _{GSSR}	V _{GS} =-20 V, V _{DS} =0 V			-100	nA
		V _{GS} =10 V, I _D =50 A			2.8	mΩ
Drain-source on-state resistance	R _{DS(on)}	V _{GS} =4.5 V, I _D =20 A			5.3	mΩ
Forward transconductance	g _{fs}	V _{DS} =10V , I _D =20A		131		S
Dynamic characteristics	·					
Input capacitance	C _{iss}			3210		
Output capacitance	C _{oss}	$V_{\rm DS} = 15 \rm V, V_{\rm GS} = 0 \rm V,$		2130		pF
Reverse transfer capacitance	C _{rss}	- F = 1MHz		343		
Turn-on delay time	t _{d(on)}			9		
Rise time	tr	$V_{DD} = 15V, V_{GS} = 10V, I_D = 20A$		4		ns
Turn-off delay time	t _{d(off)}	R _G =1.6Ω		45		
Fall time	t _f			7		1
Gate charge characteristics		· · · · · ·				
Gate to source charge	Q _{gs}			7		
Gate to drain charge	Q _{gd}	- V _{DS} =15V, I _D =15A,		17.5		nC
Gate charge total	Qg	- V _{GS} = 10 V		67		
Drain-Source diode characterist	ics and Maxi	mum Ratings				
Continuous Source Current	Is				120	A
Pulsed Source Current ⁴⁾	I _{SM}	1			360	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =40A, T _J =25℃		0.85	1.2	v
Reverse Recovery Time	t _{rr}				26	ns
Reverse Recovery Charge	Q _{rr}	I_{S} =I _F , di/dt=100A/us, T _J =25 $^{\circ}$ C ⁵⁾			95	nC

Notes:

1: The maximum junction current rating is package limited.

2: Repetitive Rating: Pulse width limited by maximum junction temperature.

3: V_DD=23V, V_GS=10V, L=0.5mH, I_{AS}=30A, R_G=25\Omega, Starting T_J=25 $^\circ\!\!\mathrm{C}.$

4: Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

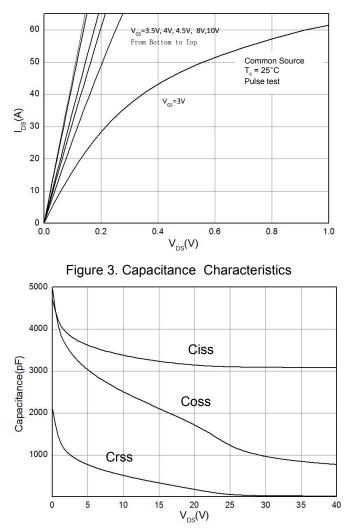
5: Guaranteed by design, not subject to production.



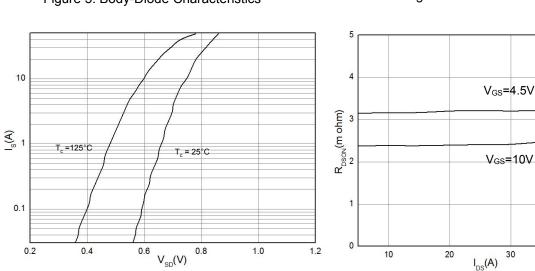
LSGG04R028/LSGH04R028

Electrical Characteristics Diagrams

Fig 1: Output Characteristics







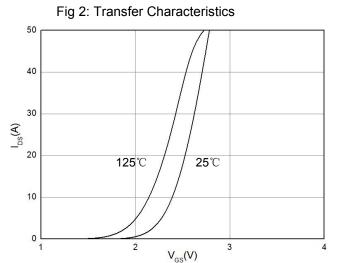


Figure 4. Gate Charge Waveform

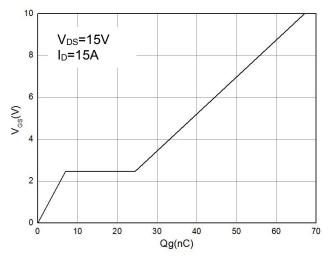


Figure 6. Rdson-Drain Current

30

50

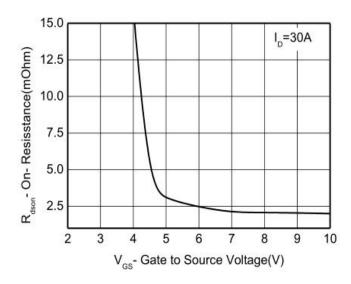
40



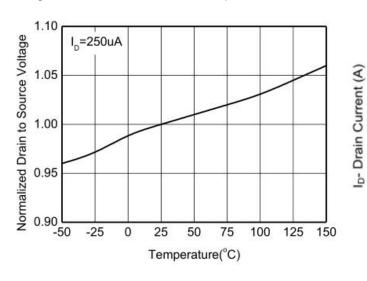
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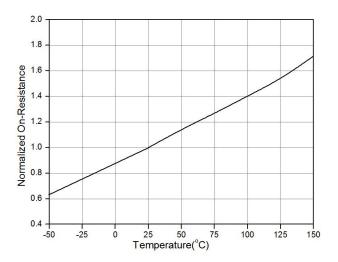
Fig 7: Rds(on) vs Gate Voltage

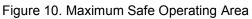
Fig 8: Rdson-Junction Temperature(°C)

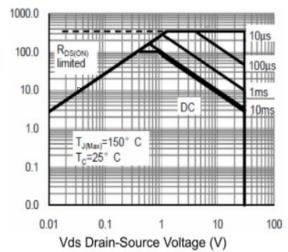




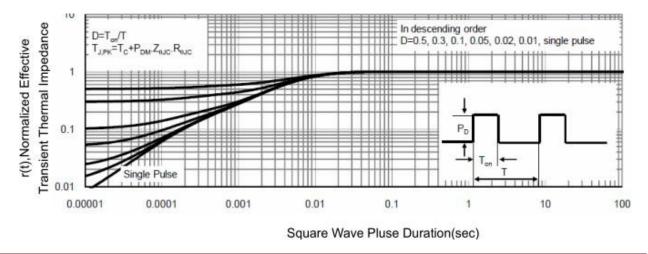








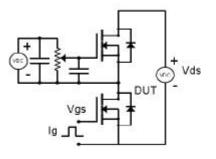


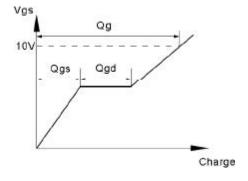


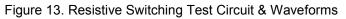


Test Circuit & Waveform

Figure 12. Gate Charge Test Circuit & Waveform







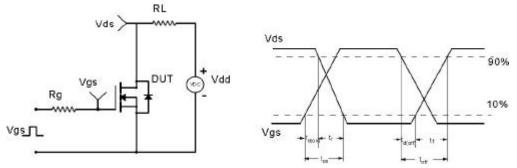


Figure 14. Unclamped Inductive Switching (UIS) Test Circuit & Waveform

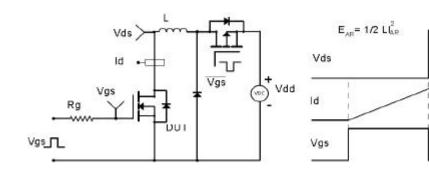
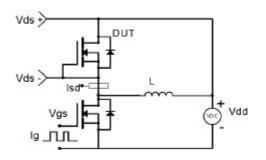
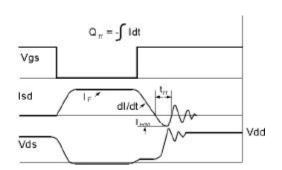


Figure 15. Diode Recovery Circuit & Waveform





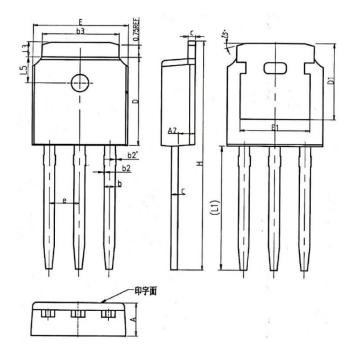
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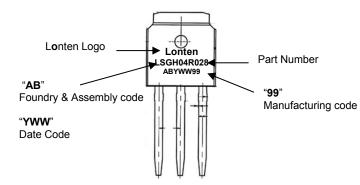


Mechanical Dimensions for TO-251



	COMMON DIMENSIONS					
SAMBOI	SYMBOL MM			INCH		
STIVIDOL	MIN	NOM	MAX	MIN	NOM	MAX
А	2.20	2.30	2.38	0.087	0.091	0.094
A2	0.97	1.07	1.17	0.038	0.042	0.046
b	0.68	0.78	0.90	0.027	0.031	0.035
b2	0.00	0.04	0.10	0.000	0.002	0.004
b2'	0.00	0.04	0.10	0.000	0.002	0.004
b3	5.20	5.33	5.46	0.205	0.210	0.215
с	0.43	0.53	0.61	0.017	0.021	0.024
D	5.98	6.10	6.22	0.235	0.240	0.245
D1		5.30REF		0.209REF		
E	6.40	6.60	6.73	0.252	0.260	0.265
E1	4.63	-	-	0.182	-	-
е	2.286BSC			().090BSC)
Н	16.22	16.52	16.82	0.639	0.650	0.662
L1	9.15	9.40	9.65	0.360	0.370	0.380
L3	0.88	1.02	1.28	0.035	0.040	0.050
L5	1.65	1.80	1.95	0.065	0.071	0.077

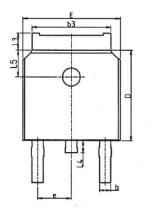
TO-251 Part Marking Information

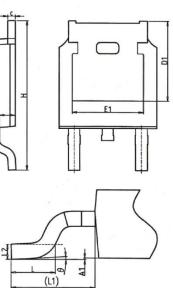


Calendar Year	Year Code	Calendar Week	Week Code
2018	G	Workweek 01	01
2019	Н	Workweek 02	02
2020	I	Workweek 03	03
2021	J	Workweek 04	04
2022	к	Workweek 05	05
2023	L	Workweek 06	06
2024	М		



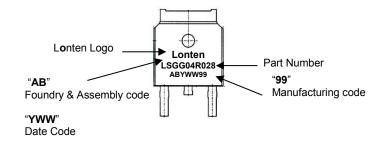
Mechanical Dimensions for TO-252





COMMON DIMENSIONS						
SYMBOL	MM			INCH		
STIVIBOL	MIN	NOM	MAX	MIN	NOM	MAX
А	2.20	2.30	2.38	0.087	0.091	0.094
A1	0.00	-	0.20	0.000	-	0.008
A2	0.97	1.07	1.17	0.038	0.042	0.046
b	0.68	0.78	0.90	0.027	0.031	0.035
b3	5.20	5.33	5.46	0.205	0.210	0.215
с	0.43	0.53	0.61	0.017	0.021	0.024
D	5.98	6.10	6.22	0.235	0.240	0.245
D1		5.30REF	-	0.209REF		
E	6.40	6.60	6.73	0.252	0.260	0.265
E1	4.63	-	-	0.182	-	-
е		2.286BS	0	0.090BSC		
Н	9.40	10.10	10.50	0.370	0.398	0.413
L	1.38	1.50	1.75	0.054	0.059	0.069
L1		2.90REF	-		0.114REF	:
L2	0.51BSC			0.020BSC	;	
L3	0.88	-	1.28	0.035	-	0.050
L4	0.50	-	1.00	0.020	-	0.039
L5	1.65	1.80	1.95	0.065	0.071	0.077
θ	0°	-	8°	0°	-	8°

TO-252 Part Marking Information



Calendar Year	Year Code	Calendar Week	Week Code
2018	G	Workweek 01	01
2019	Н	Workweek 02	02
2020	I	Workweek 03	03
2021	J	Workweek 04	04
2022	к	Workweek 05	05
2023	L	Workweek 06	06
2024	М		



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